

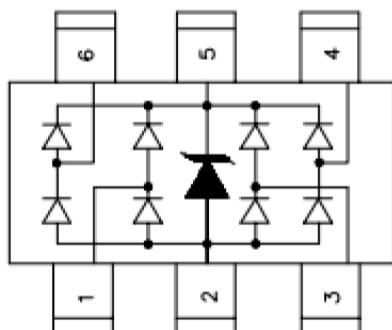
Description

The JE05U4RT20-6A is a low capacitance TVS arrays, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The JE05U4RT20-6A complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 25\text{kV}$ contact discharge. It is assembled into a 6-lead SOT23-6L leadfree package. The leads are finished with lead-free matte tin. Each device will protect up to four high-speed lines. The combination of small size, low capacitance, and high surge capability makes them ideal for use in applications such as Ethernet, USB 2.0, and video interfaces.

Features

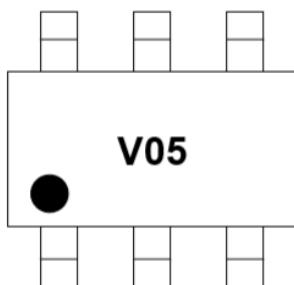
- * Low capacitance: 0.8pF typical (I/O to I/O)
- * Low leakage: nA level
- * Operating voltage: 5V
- * Low clamping voltage
- * Up to four lines and one power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 25\text{kV}$
 - IEC 61000-4-5 (Lightning) 8A (8/20 μs)
- * RoHS Compliant
- * Package: SOT23-6L

Circuit Diagram



Circuit and Pin Schematic

Marking Diagram



V05 = Device Marking Code
Dot denotes Pin1

Applications

- * USB 2.0 power and data line
- * Monitors and flat panel displays
- * Set-top box and digital TV
- * Digital visual interface (DVI)
- * Notebook Computers
- * SIM Ports
- * Gigabit Ethernet

Ordering Information

Part Number	Packaging	Reel Size
JE05U4RT20-6A	3000/Tape & Reel	7 inch

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	160	W
Peak Pulse Current (8/20μs)	IPP	8	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±30 ±25	kV
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

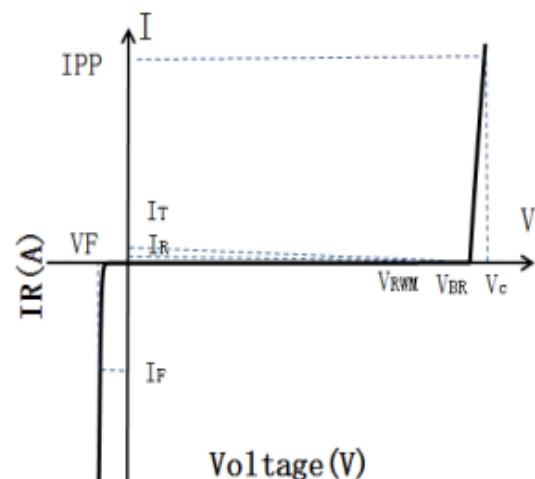
Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	Pin 5 to Pin 2
Breakdown Voltage	V _{BR}	6			V	I _T = 1mA, Pin 5 to Pin 2
Reverse Leakage Current	I _R			0.2	μA	V _{RWM} = 5V, Pin 5 to Pin 2
Forward Voltage	V _F			1.2	V	I _F = 15mA
Clamping Voltage	V _C			12	V	IPP = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	V _C			20	V	IPP = 8A (8 x 20μs pulse), any I/O pin to ground
Junction Capacitance	C _J			0.8	pF	V _R = 0V, f = 1MHz, between I/O pins
Junction Capacitance	C _J			1.5	pF	V _R = 0V, f = 1MHz, any I/O pin to ground

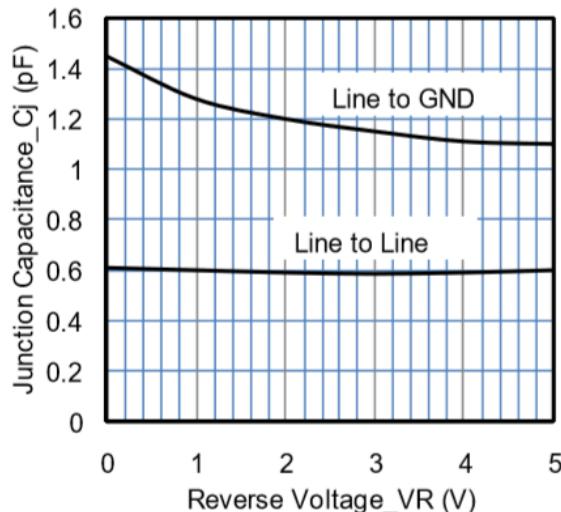
Note 1: I/O pins are Pin 1, 3, 4 and 6

Portion Electronics Parameter

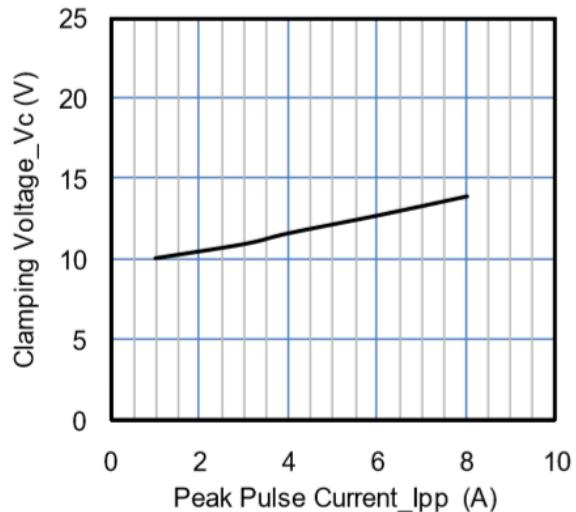
Symbol	Parameter
I _T	Test Current
IPP	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @I _c



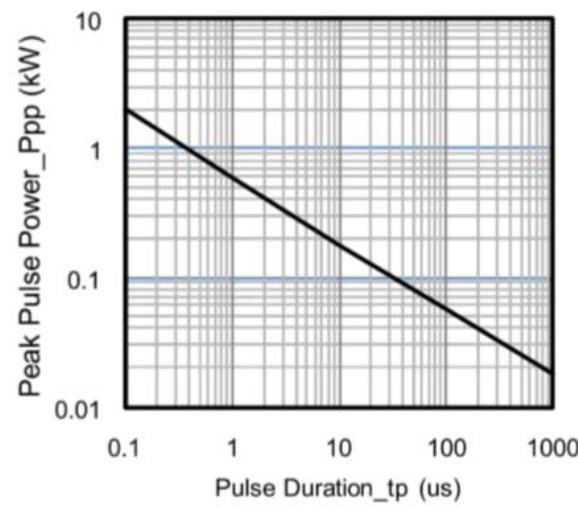
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



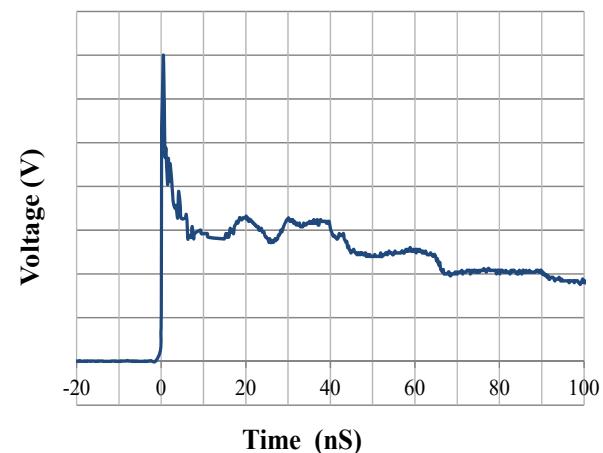
Junction Capacitance vs. Reverse Voltage



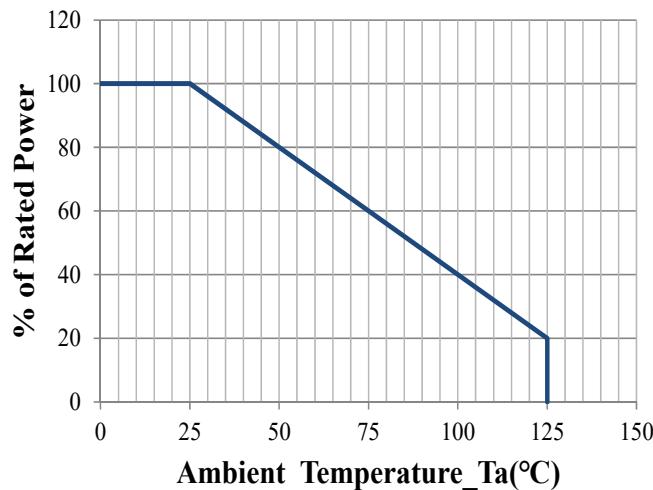
Clamping Voltage vs. Peak Pulse Current



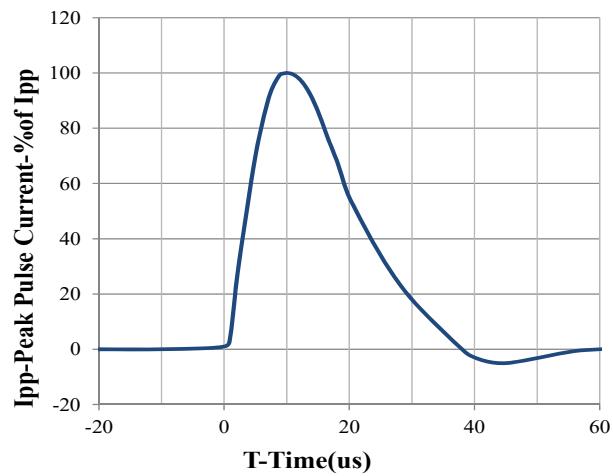
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform

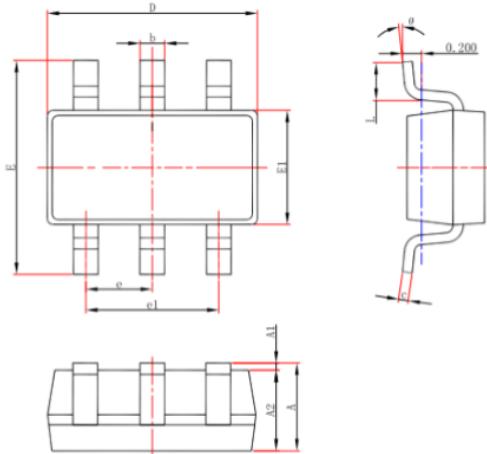


Power Derating Curve



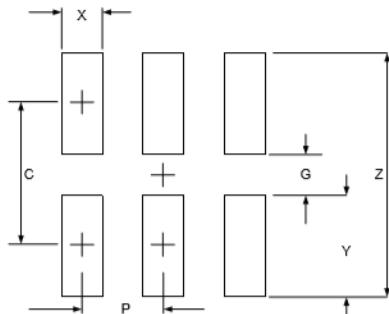
8 X 20us Pulse Waveform

SOT23-6L Package Outline Drawing



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	2.50	0.098
G	1.40	0.055
P	0.95	0.037
X	0.60	0.024
Y	1.10	0.043
Z	3.60	0.141

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